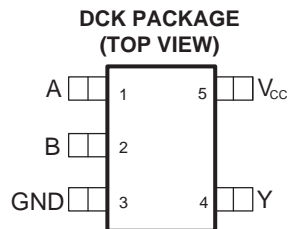


## 低功耗单路 2 输入正与门

 查询样品: [SN74AUP1G08-Q1](#)

### 特性

- 具有符合 **AEC-Q100** 的下列结果:
  - 器件温度 1 级: **-40°C 至 125°C** 的环境运行温度范围
  - 器件人体模型 (HBM) 静电放电 (ESD) 分类等级 **H2**
  - 器件充电器件模型 (CDM) ESD 分类等级 **C3B**
- 采用德州仪器的 **NanoStar™** 封装
- 低静态功耗:
  - I<sub>CC</sub>=0.9μA** (最大值)
- 低动态功耗: **3.3V** 时的典型值,
  - C<sub>pd</sub>=4.3pF**
- 低输入电容: **C<sub>i</sub>=1.5pF** (典型值)
- 低噪声: 过冲和下冲  
小于 **V<sub>CC</sub>** 的 **10%**
- **I<sub>关闭</sub>** 支持部分断电模式运行
- 施密特触发器的运行可实现低输入转换以及输入上更好的开关噪声抗扰度 (**V<sub>hys</sub>=250mV**, 这是 **3.3V** 时的典型值)
- **0.8V 至 3.6V** 的宽运行 **V<sub>CC</sub>** 范围
- 针对 **3.3V** 运行进行了优化
- 可耐受 **3.6V** 输入/输出 (I/O) 以支持混合模式信号运行
- **3.3V** 时, **t<sub>pd</sub>=4.3ns** (最大值)
- 适合于点到点应用
- 锁存性能超过 **100mA** (符合 **JESD-78, II** 类规范的要求)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

NanoStar is a trademark of Texas Instruments.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

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English Data Sheet: [SCES847](#)

## 说明

AUP 系列产品是 TI 针对业界对于电池供电便携式应用的低功耗需求的主要解决方案。此系列可确保在整个 0.8V 至 3.6V 的  $V_{CC}$  范围内实现超低静态和动态功耗，从而延长电池的使用寿命（请见图 1）。这个产品还保持了出色的信号完整性（请见图 2 中显示的极低下冲和上冲特性）。

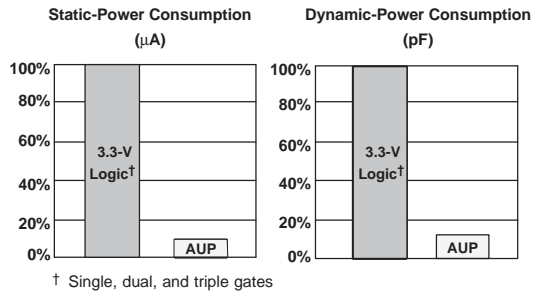


图 1. AUP - 最低功耗系列

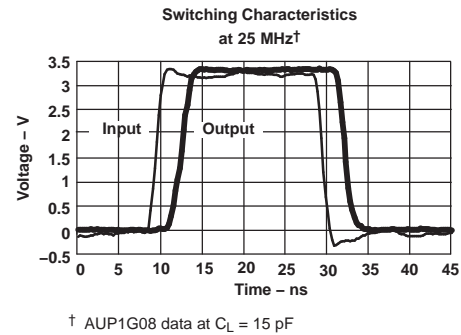


图 2. 出色的信号完整性

这个单路 2 输入正与门执行布尔函数：正逻辑中的  $Y = A \cdot B$  or  $Y = \overline{\overline{A} + \overline{B}}$ 。

NanoStar 封装技术是集成电路 (IC) 封装理念的重要突破，这是因为此技术使用芯片作为封装。

该器件完全符合使用  $I_{\text{关闭}}$  的部分断电应用的规范要求。 $I_{\text{关闭}}$  电路禁用输出，从而可防止其断电时破坏性电流从该器件回流。



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### ORDERING INFORMATION<sup>(1)</sup>

$T_A$	ORDERABLE PART NUMBER <sup>(2)</sup>	TOP-SIDE MARKING
-40°C to 125°C	SN74AUP1G08QDCKRQ1	SIT

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at [www.ti.com](http://www.ti.com).
- (2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).

**FUNCTION TABLE**

INPUTS		OUTPUT Y
A	B	
L	L	L
L	H	L
H	L	L
H	H	H

**LOGIC DIAGRAM (POSITIVE LOGIC)**



**ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range	-0.5	4.6	V	
V <sub>I</sub>	Input voltage range <sup>(2)</sup>	-0.5	4.6	V	
V <sub>O</sub>	Voltage range applied to any output in the high-impedance or power-off state <sup>(2)</sup>	-0.5	4.6	V	
V <sub>O</sub>	Output voltage range in the high or low state <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±20	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature range	-65	150	°C	
ESD ratings	Human body model (HBM) AEC-Q100 classification level H2			2	kV
	Charged device model (CDM) AEC-Q100 classification level C3B			750	V

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

**THERMAL INFORMATION**

THERMAL METRIC <sup>(1)</sup>		SN74AUP1G08-Q1	UNIT
		DCK (5 PINS)	
θ <sub>JA</sub>	Junction-to-ambient thermal resistance	304.7	°C/W
θ <sub>JCtop</sub>	Junction-to-case (top) thermal resistance	115.3	
θ <sub>JB</sub>	Junction-to-board thermal resistance	80.3	
ψ <sub>JT</sub>	Junction-to-top characterization parameter	3.5	
ψ <sub>JB</sub>	Junction-to-board characterization parameter	79.4	
θ <sub>JCbot</sub>	Junction-to-case (bottom) thermal resistance	N/A	

- (1) 有关传统和新的热 度量的更多信息，请参阅 *IC 封装热度量应用报告*，SPRA953。

**RECOMMENDED OPERATING CONDITIONS<sup>(1)</sup>**

		MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage	0.8	3.6	V
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.65 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.6	
		V <sub>CC</sub> = 3 V to 3.6 V	2	
V <sub>IL</sub>	Low-level input voltage	V <sub>CC</sub> = 0.8 V	0	V
		V <sub>CC</sub> = 1.1 V to 1.95 V	0.35 × V <sub>CC</sub>	
		V <sub>CC</sub> = 2.3 V to 2.7 V	0.7	
		V <sub>CC</sub> = 3 V to 3.6 V	0.9	
V <sub>I</sub>	Input voltage	0	3.6	V
V <sub>O</sub>	Output voltage	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 0.8 V	-20	μA
		V <sub>CC</sub> = 1.1 V	-1.1	
		V <sub>CC</sub> = 1.4 V	-1.7	
		V <sub>CC</sub> = 1.65 V	-1.9	
		V <sub>CC</sub> = 2.3 V	-3.1	
		V <sub>CC</sub> = 3 V	-4	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 0.8 V	20	μA
		V <sub>CC</sub> = 1.1 V	1.1	
		V <sub>CC</sub> = 1.4 V	1.7	
		V <sub>CC</sub> = 1.65 V	1.9	
		V <sub>CC</sub> = 2.3 V	3.1	
		V <sub>CC</sub> = 3 V	4	
Δt/Δv	Input transition rise or fall rate	V <sub>CC</sub> = 0.8 V to 3.6 V	200	ns/V
T <sub>A</sub>	Operating free-air temperature	-40	125	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See the TI application report *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#).

**ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		T <sub>A</sub> = 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = -20 μA	0.8 V to 3.6 V	V <sub>CC</sub> - 0.1			V <sub>CC</sub> - 0.1		V <sub>CC</sub> - 0.1		V
	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>			0.7 × V <sub>CC</sub>		0.7 × V <sub>CC</sub>		
	I <sub>OH</sub> = -1.7 mA	1.4 V	1.11			1.03		1.03		
	I <sub>OH</sub> = -1.9 mA	1.65 V	1.32			1.3		1.3		
	I <sub>OH</sub> = -2.3 mA	2.3 V	2.05			1.97		1.97		
	I <sub>OH</sub> = -3.1 mA		1.9			1.85		1.85		
	I <sub>OH</sub> = -2.7 mA	3 V	2.72			2.67		2.67		
	I <sub>OH</sub> = -4 mA		2.6			2.55		2.55		

**ELECTRICAL CHARACTERISTICS (continued)**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		T <sub>A</sub> = 125°C		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
V <sub>OL</sub>	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V			0.1		0.1		0.1	V
	I <sub>OL</sub> = 1.1 mA	1.1 V			0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>	
	I <sub>OL</sub> = 1.7 mA	1.4 V			0.31		0.37		0.37	
	I <sub>OL</sub> = 1.9 mA	1.65 V			0.31		0.35		0.35	
	I <sub>OL</sub> = 2.3 mA	2.3 V			0.31		0.33		0.33	
	I <sub>OL</sub> = 3.1 mA				0.44		0.45		0.45	
	I <sub>OL</sub> = 2.7 mA	3 V			0.31		0.33		0.33	
	I <sub>OL</sub> = 4 mA				0.44		0.45		0.45	
I <sub>I</sub>	A or B input	V <sub>I</sub> = GND to 3.6 V			0.1		0.5		0.5	μA
I <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V			0.2		0.6		0.8	μA
ΔI <sub>off</sub>		V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V			0.2		0.6		0.8	μA
I <sub>CC</sub>		V <sub>I</sub> = GND or (V <sub>CC</sub> to 3.6 V), I <sub>O</sub> = 0			0.5		0.9		1.2	μA
ΔI <sub>CC</sub>		V <sub>I</sub> = V <sub>CC</sub> - 0.6 V <sup>(1)</sup> , I <sub>O</sub> = 0			40		50		23	μA
C <sub>i</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	0 V			1.5					pF
		3.6 V			1.5					
C <sub>o</sub>	V <sub>O</sub> = GND	0 V			3					pF

 (1) One input at V<sub>CC</sub> - 0.6 V, other input at V<sub>CC</sub> or GND.

**SWITCHING CHARACTERISTICS**

 over recommended operating free-air temperature range, C<sub>L</sub> = 5 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	0.8 V		18				ns
			1.2 V ± 0.1 V	2.6	7.3	12.8	2.1	15.6	
			1.5 V ± 0.1 V	1.4	5.2	8.7	0.9	10.3	
			1.8 V ± 0.15 V	1	4.2	6.6	0.5	8.2	
			2.5 V ± 0.2 V	1	3	4.4	0.5	5.5	
			3.3 V ± 0.3 V	1	2.4	3.5	0.5	4.3	

**SWITCHING CHARACTERISTICS**

 over recommended operating free-air temperature range, C<sub>L</sub> = 10 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	0.8 V		21				ns
			1.2 V ± 0.1 V	1.5	8.5	14.7	1	17.2	
			1.5 V ± 0.1 V	1	6.2	10	0.5	11.3	
			1.8 V ± 0.15 V	1	5	7.7	0.5	9	
			2.5 V ± 0.2 V	1	3.6	5.2	0.5	6.1	
			3.3 V ± 0.3 V	1	2.9	4.2	0.5	4.7	

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 15$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C to } 85^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	
$t_{pd}$	A or B	Y	0.8 V	24					ns
			$1.2\text{ V} \pm 0.1\text{ V}$	3.6	9.9	16.3	3.1	19.9	
			$1.5\text{ V} \pm 0.1\text{ V}$	2.3	7.2	11.1	1.8	13.2	
			$1.8\text{ V} \pm 0.15\text{ V}$	1.6	5.8	8.7	1.1	10.6	
			$2.5\text{ V} \pm 0.2\text{ V}$	1	4.3	5.9	0.5	7.3	
			$3.3\text{ V} \pm 0.3\text{ V}$	1	3.4	4.8	0.5	5.9	

## SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 30$  pF (unless otherwise noted) (see [Figure 3](#) and [Figure 4](#))

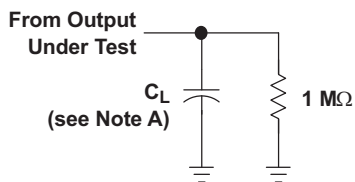
PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC}$	$T_A = 25^\circ\text{C}$			$T_A = -40^\circ\text{C to } 85^\circ\text{C}$		$T_A = 125^\circ\text{C}$		UNIT
				MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$t_{pd}$	A or B	Y	0.8 V	32.8							ns
			$1.2\text{ V} \pm 0.1\text{ V}$	4.9	13.1	20.9	4.4	25.5	4.4	27.8	
			$1.5\text{ V} \pm 0.1\text{ V}$	3.4	9.5	14.2	2.9	16.9	2.9	18	
			$1.8\text{ V} \pm 0.15\text{ V}$	2.5	7.7	11	2	13.5	2	19.7	
			$2.5\text{ V} \pm 0.2\text{ V}$	1.8	5.7	7.6	1.3	9.4	1.3	11	
			$3.3\text{ V} \pm 0.3\text{ V}$	1.5	4.7	6.2	1	7.5	1	8.7	

## OPERATING CHARACTERISTICS

$T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	$V_{CC}$	TYP	UNIT
$C_{pd}$	Power dissipation capacitance	$f = 10\text{ MHz}$	0.8 V	4	pF
			$1.2\text{ V} \pm 0.1\text{ V}$	4	
			$1.5\text{ V} \pm 0.1\text{ V}$	4	
			$1.8\text{ V} \pm 0.15\text{ V}$	4	
			$2.5\text{ V} \pm 0.2\text{ V}$	4.1	
			$3.3\text{ V} \pm 0.3\text{ V}$	4.3	

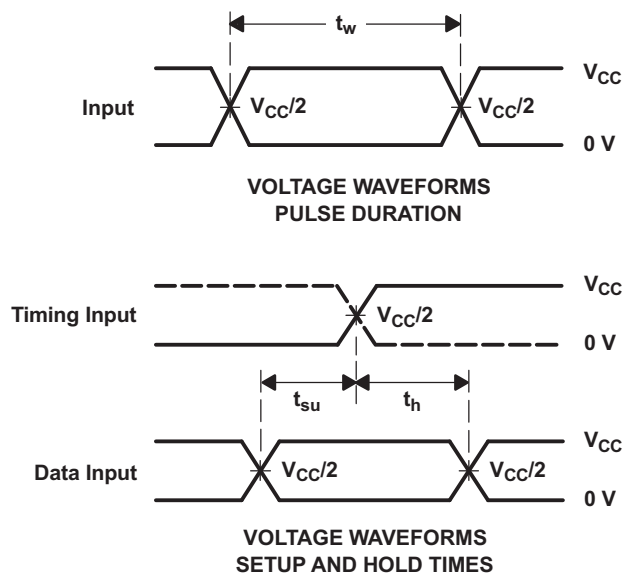
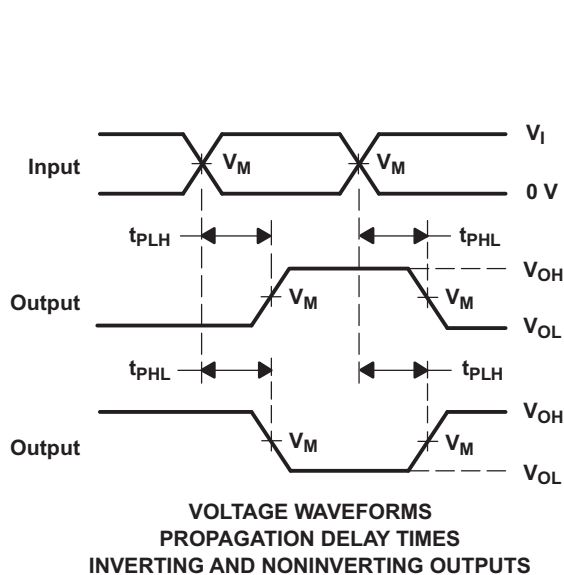
**PARAMETER MEASUREMENT INFORMATION**  
(Propagation Delays, Setup and Hold Times, and Pulse Duration)



LOAD CIRCUIT

$T_A = -25^\circ\text{C to } 85^\circ\text{C}$

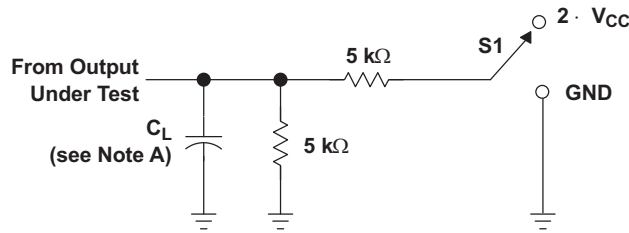
	$V_{CC} = 0.8\text{ V}$	$V_{CC} = 1.2\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.5\text{ V} \pm 0.1\text{ V}$	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$	$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$	$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$
$C_L$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
$V_M$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_I$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$



- NOTES: A.  $C_L$  includes probe and jig capacitance.  
 B. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ , slew rate  $\geq 1\text{ V/ns}$ .  
 C. The outputs are measured one at a time, with one transition per measurement.  
 D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .  
 E. All parameters and waveforms are not applicable to all devices.

**Figure 3. Load Circuit and Voltage Waveforms**

**PARAMETER MEASUREMENT INFORMATION  
(Enable and Disable Times)**

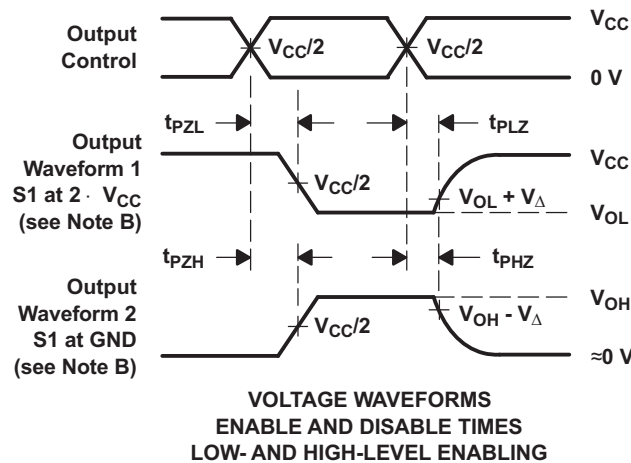


TEST	S1
$t_{PLZ}/t_{PZL}$	$2 \cdot V_{CC}$
$t_{PHZ}/t_{PHL}$	GND

**LOAD CIRCUIT**

$T_A = -25^\circ\text{C to } 85^\circ\text{C}$

	$V_{CC} = 0.8 \text{ V}$	$V_{CC} = 1.2 \text{ V} \pm 0.1 \text{ V}$	$V_{CC} = 1.5 \text{ V} \pm 0.1 \text{ V}$	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$
$C_L$	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
$V_M$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$	$V_{CC}/2$
$V_I$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$	$V_{CC}$
$V_\Delta$	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



**VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING**

- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ , slew rate  $\geq 1 \text{ V/ns}$ .
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G. All parameters and waveforms are not applicable to all devices.

**Figure 4. Load Circuit and Voltage Waveforms**



**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP1G08QDCKRQ1	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(SIJ, SIT)	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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**OTHER QUALIFIED VERSIONS OF SN74AUP1G08-Q1 :**

- Catalog : [SN74AUP1G08](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

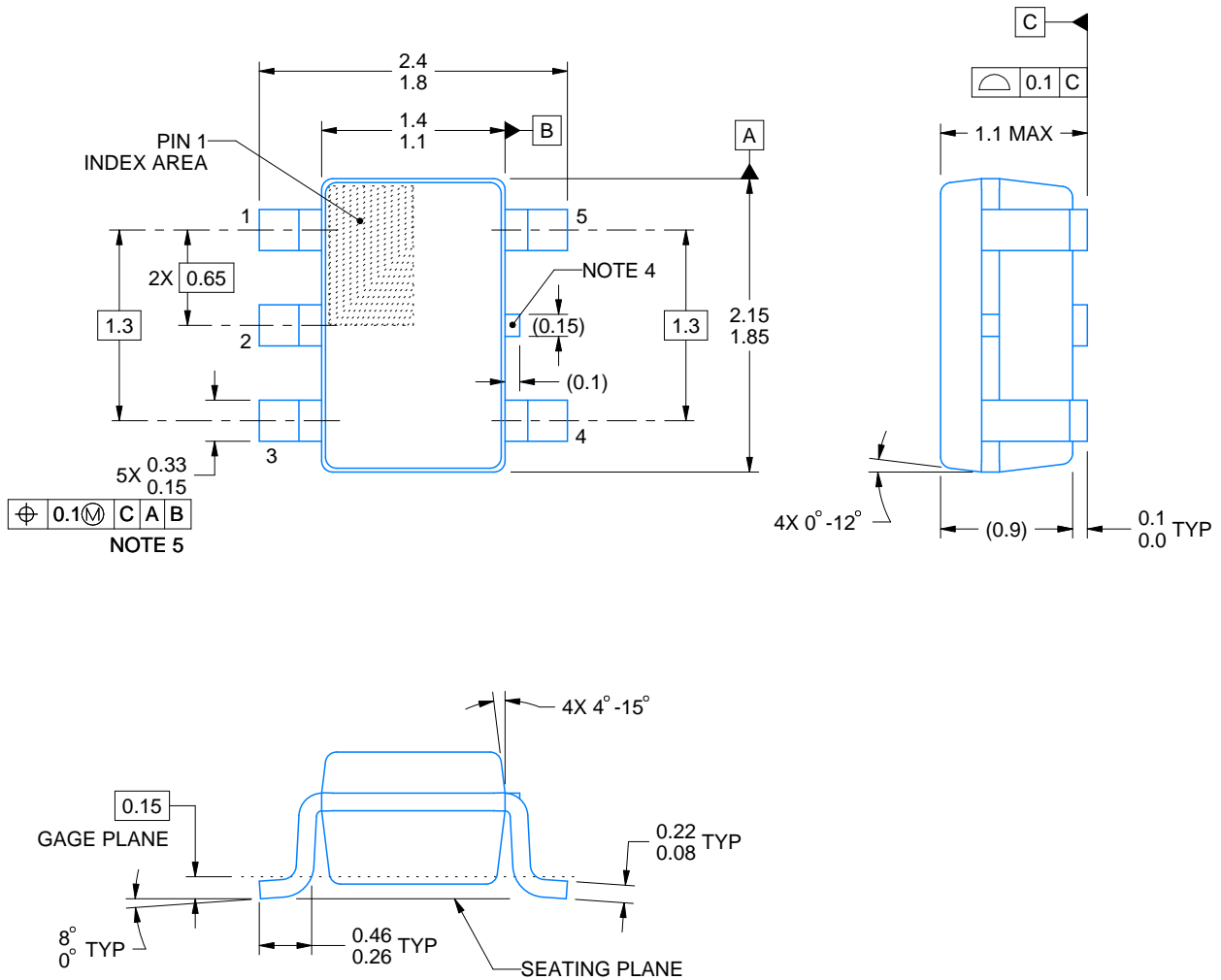
# DCK0005A



# PACKAGE OUTLINE

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



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## NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

# EXAMPLE BOARD LAYOUT

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



SOLDER MASK DETAILS

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NOTES: (continued)

- 7. Publication IPC-7351 may have alternate designs.
- 8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE: 18X

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NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.

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